### CMOS DIGITAL INTEGRATED CIRCUIT

## 2-Input And Gate

The TC7S08 is a high speed C2MOS 2-input And Gate fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves high speed operation similar to equivalent LSTTL while maintaining the C<sup>2</sup>MOS low power dissipation.

The internal circuit is composed of 2 stages including buffer output, which enables high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

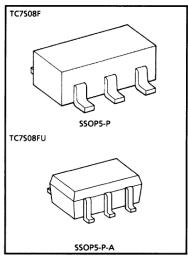
Output currents are 1/2 compared to TC74HC series models.

#### **Features**

- High speed
- t<sub>pd</sub> = 7ns (Typ.) at V<sub>CC</sub> = 5V
  Low Power Dissipation
- I<sub>CC</sub> = 1μA (Max.) at Ta = 25°C
  High Noise Immunity
- V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (Min.)
  Output Drive Capability
- 5 LSTTL Loads
- Symmetrical Output Impedance
  - $II_{OH}I = I_{OL} = 2mA$  (Min.)
- Balanced Propagation Delays
  - $t_{pLH} = t_{pHL}$
- Wide Operating Voltage Range
  - $V_{CC(opr)} = 2 \sim 6V$

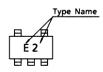
### **Maximum Ratings**

Characteristics	Symbol	Condition	Unit
Supply Voltage Range	V <sub>CC</sub>	-0.5~7	V
DC Input Voltage	V <sub>IN</sub>	-0.5~V <sub>CC</sub> + 0.5	V
DC Output Voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5	V
Input Diode Current	I <sub>IK</sub>	±20	mA
Output Diode Current	lok	±20	mA
DC Output Current	l <sub>OUT</sub>	±12.5	mA
DC V <sub>CC</sub> / Ground Current	I <sub>CC</sub>	±25	mA
Power Dissipation	P <sub>D</sub>	200	mW
Storage Temperature	T <sub>stg</sub>	-65~150	°C
Lead Temperature (10s)	TL	260	°C

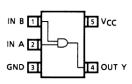


Weight SSOP5-P : 0.016g (Typ.) SSOP5-P-A : 0.006g (Typ.)

### Marking



#### Pin Assignment (Top View)



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# **Logic Diagram**

# **Recommended Operating Conditions**

Characteristics	Symbol	Condition	Unit
Supply Voltage	V <sub>CC</sub>	2~6	V
Input Voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output Voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	-40~85	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	0~1000 (V <sub>CC</sub> = 2.0V) 0~ 500 (V <sub>CC</sub> = 4.5V) 0~ 400 (V <sub>CC</sub> = 6.0V)	ns

### **DC Electrical Characteristics**

Characteristic	Symbol	Test Condition V <sub>CC</sub>		Ta = 25°C			Ta = -40~85°C		Unit	
Gilalacteristic	Syllibol			V <sub>CC</sub>	Min.	Тур.	Max.	Min.	Max	
High-Level Input Voltage	V <sub>IH</sub>	-		2.0 4.5 6.0	1.5 3.15 4.2	- - -	- - -	1.5 3.15 4.2	- - -	V
Low-Level Input Voltage	V <sub>IL</sub>	-		2.0 4.5 6.0	- - -	- - -	0.5 1.35 1.8	- - -	0.5 1.35 1.8	V
High-Level Output Voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$	I <sub>OH</sub> = -20 μA	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	- - -	1.9 4.4 5.9	- - -	V
			$I_{OH} = -2mA$ $I_{OH} = -2.6mA$	4.5 6.0	4.18 5.68	4.31 5.80	_ _	4.13 5.63	_ _	
Low-Level Output Voltage $V_{OL}$ $V_{IN} = $ or $V_{IN} = $	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2.0 4.5 6.0		0.0 0.0 0.0	0.1 0.1 0.1	-   -   -	0.1 0.1 0.1	V	
			$I_{OL} = 2mA$ $I_{OL} = 2.6mA$	4.5 6.0	1	0.17 0.18	0.26 0.26	_ _	0.33 0.33	
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V$	V <sub>IN</sub> = V <sub>CC</sub> or GND		_	_	±0.1	_	±0.1	μΑ
Quiescent Supply Current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	_	1.0	_	10.0	μι

Output currents are 1/2 compared to TC74HC series models.

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# AC Electrical Characteristics ( $C_L = 15pF$ , Input $t_r = t_f = 6ns$ , $V_{CC} = 5V$ )

Characteristic	Symbol	Test Condition		Unit		
	Oymboi	rest obligation	Min.	Тур.	Max.	
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>	_	_	5	10	ns
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>	_	_	7	15	ns

## AC Electrical Characteristics ( $C_L = 50pF$ , Input $t_r = t_f = 6ns$ )

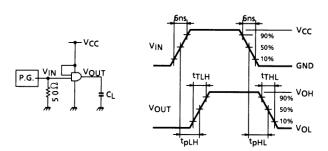
Characteristic	Symbol	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit
			V <sub>CC</sub>	Min.	Typ.	Max.	Min.	Max	
Output Transition Time	t <sub>TLH</sub>	_	2.0 4.5 6.0	- - -	50 14 12	125 25 21	- - -	155 31 26	ns
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>	_	2.0 4.5 6.0	- - -	48 12 9	100 20 17	- - -	125 25 21	ns
Input Capacitance	C <sub>IN</sub>	_	•	_	5	10	_	10	pF
Power Dissipation Capacitance	C <sub>PD</sub>	(Note 1)		_	10	-	_	_	Pi

Note 1: C<sub>PD</sub> defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit).

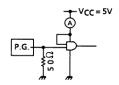
Average operating current can be obtained by the equation hereunder.

$$I_{CC \text{ (opr)}} = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$$

## **Switching Characteristics Test Circuit**



# I<sub>CC (opr)</sub> Test Circuit



Input waveform is the same as that in case of switching characteristics test.

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